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March 2008

SG6859A
Low-Cost, Green-Mode PWM Controller for Flyback Converters

Features

- Green-Mode PWM
- Supports the “Blue Angel” Standard
- Low Start-up Current: 9μA
- Low Operating Current: 3mA
- Leading-Edge Blanking
- Constant Output Power Limit
- Universal Input
- Built-in Synchronized Slope Compensation
- Current-Mode Operation
- Cycle-by-cycle Current Limiting
- Under-Voltage Lockout (UVLO)
- Programmable PWM Frequency with Frequency Hopping
- V_{DD} Over-Voltage Protection (Auto Restart)
- Gate Output Voltage Clamped at 17V
- Low Cost
- Few External Components Required
- Small SOT-26 Package

Applications

General-purpose switching mode power supplies and flyback power converters, such as:

- Battery chargers for cellular phones, cordless phones, PDAs, digital cameras, and power tools
- Power adapters for ink jet printers, video game consoles, and portable audio players
- Open-frame SMPS for TV/DVD standby and auxiliary supplies, home appliances, and consumer electronics
- Replacements for linear transformers and RCC SMPS
- PC 5V standby power

Description

This highly integrated PWM controller provides several enhancements designed to meet the low standby-power needs of low-power SMPS. To minimize standby power consumption, the proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load conditions. This green-mode function enables the power supply to meet even the strictest power conservation requirements.

The BiCMOS fabrication process enables reducing the start-up current to 9μA and the operating current to 3mA. To further improve power conservation, a large start-up resistance can be used. Built-in synchronized slope compensation ensures the stability of peak current mode control. Proprietary internal compensation provides a constant output power limit over a universal AC input range ($90V_{AC}$ to $264V_{AC}$). Pulse-by-pulse current limiting ensures safe operation during short-circuits.

To protect the external power MOSFET from damage by supply over voltage, the SG6859A’s output driver is clamped at 17V. SG6859A controllers can be used to improve the performance and reduce the production cost of power supplies. The best choice for replacing linear and RCC-mode power adapters, the SG6859A is available in 8-pin DIP and 6-pin SOT-26 packages.

Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method
SG6859ATZ	-20°C to +85°C	SOT-26	Tape & reel
SG6859ADZ	-20°C to +85°C	DIP-8	Tube

All packages are lead free per JEDEC: J-STD-020B standard.

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Application Diagram

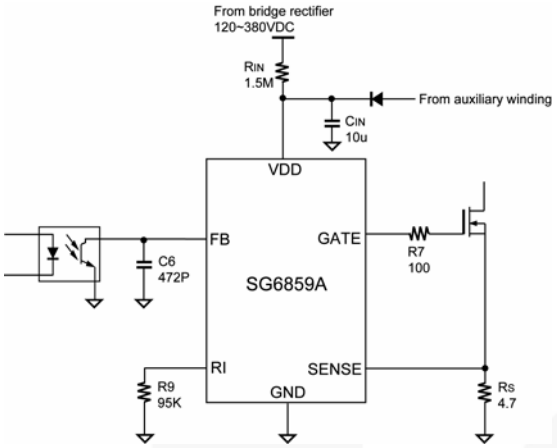


Figure 1. Typical Application

Internal Block Diagram

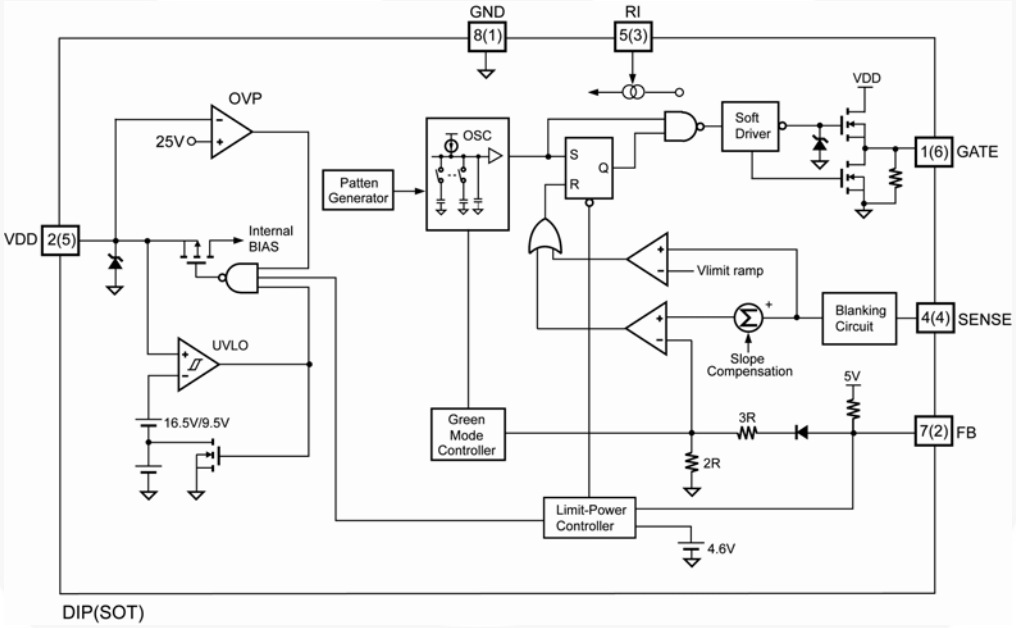


Figure 2. Functional Block Diagram

Pin Configuration

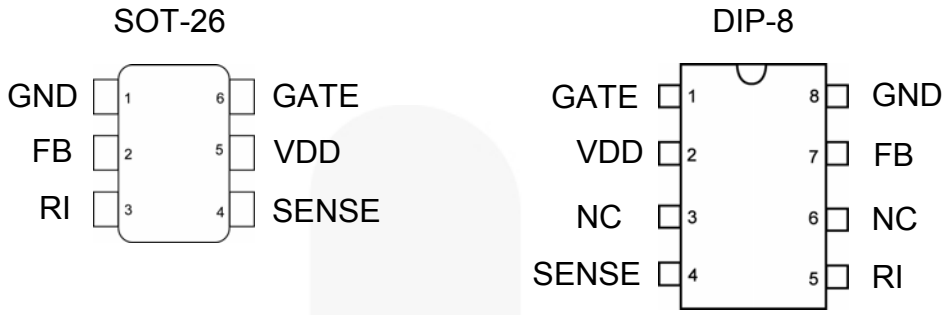


Figure 3. Pin Configurations

Pin Definitions

DIP Pin #	SOT Pin #	Name	Description
1	6	GATE	The totem-pole output driver for driving the power MOSFET.
2	5	VDD	Power supply.
3		NC	No connection
4	4	SENSE	Current sense. This pin senses the voltage across a resistor. When the voltage reaches the internal threshold, PWM output is disabled. This activates over-current protection. This pin also provides current amplitude information for current-mode control.
5	3	RI	A resistor connected from the RI pin to ground generates a constant current source used to charge an internal capacitor and determine the switching frequency. Increasing the resistance reduces the amplitude of the current source and the switching frequency. A 95kΩ resistor R_I results in a 50μA constant current I_I and a 70kHz switching frequency.
6		NC	No connection
7	2	FB	Feedback. The FB pin provides the output voltage regulation signal. It provides feedback to the internal PWM comparator, so that the PWM comparator can control the duty cycle.
8	1	GND	Ground.

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Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V_{VDD}	DC Supply Voltage[1, 2]			30	V
V_{FB}	Input Voltage to FB Pin		-0.3	7.0	V
V_{SENSE}	Input Voltage to Sense Pin		-0.3	7.0	V
T_J	Operating Junction Temperature			150	°C
Θ_{JA}	Thermal Resistance (Junction-to-Air)	SOT		208.4	°C/W
		DIP		82.5	°C/W
T_{STG}	Storage Temperature Range		-55	150	°C
T_L	Lead Temperature (Wave Soldering or IR, 10 Seconds)			260	°C
ESD	Electrostatic Discharge Capability, Human Body Model			3.5	kV
	Electrostatic Discharge Capability, Machine Model			200	V

Notes:
1. All voltage values, except differential voltages, are given with respect to GND pin.
2. Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device.

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Electrical Characteristics

Unless otherwise noted, V_{DD}=15V and T_A=25°C.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{DD} Section						
V_{DD-OP}	Continuously Operation Voltage				22	V
V_{DD-ON}	Turn-on Threshold Voltage		15.5	16.5	17.5	V
V_{DD-OFF}	Turn-off Threshold Voltage		8.5	9.5	10.5	V
I_{DD-ST}	Startup Current	$V_{DD}=V_{DD-ON}$ – 0.1V		9	15	μA
I_{DD-OP}	Operating Supply Current	V_{DD}=15V, C_L=1nF		3.0	3.5	mA
V_{DD-OVP}	V_{DD} Over-voltage Protection Level	Auto Restart	24	25	26	V
$t_{D-VDDOVP}$	V_{DD} Over-voltage Protection Debounce	Auto Restart		125		μs
$V_{DD-G\ OFF}$	V_{DD} Low-threshold Voltage to Exit Green-off Mode			V_{DD-OFF} + 1		V
Feedback Input Section						
Z_{FB}	Input Impedance			5		kΩ
$V_{FB-OPEN}$	FB Output High Voltage		5			V
V_{FB-OL}	FB Open-loop Trigger Level		4.3	4.6	4.9	V
t_{D-OLP}	Delay of FB Pin Open-loop Protection			56		ms
V_{FB-N}	Green-Mode Entry FB Voltage		2.60	2.85	3.10	V
V_{FB-G}	Green-Mode Ending FB Voltage			2.2		V
S_G	Green-Mode Modulation Slope	R_I=95kΩ	40	75	100	Hz/mV
Current-Sense Section						
Z_{SENSE}	Input Impedance		10			kΩ
t_{PD}	Delay to Output		40	55	100	ns
V_{STHFL}	Flat Threshold Voltage for Current Limit			1		V
V_{STHVA}	Valley Threshold Voltage for Current Limit		0.75	0.80	0.85	V
t_{LEB}	Leading-Edge Blanking Time		270	320	370	ns
DCY_{SAW}	Duty Cycle of SAW Limit			40		%
Oscillator Section						
F_{OSC}	Frequency — Center Frequency	R_I=95kΩ	65	70	75	kHz
	Frequency — Hopping Range			±4.9		
T_{HOP}	Hopping Period	R_I=95kΩ		3.7		ms
F_{OSC-G}	Green-Mode Frequency	R_I=95kΩ		20		kHz
F_{DV}	Frequency Variation vs. V_{DD} Deviation	V_{DD}=13.5 to 22V	0	0.02	2.00	%
F_{DT}	Frequency Variation vs. Temperature Deviation	T_A=-20 to 85°C			2	%
Output Section						
DCY_{MAX}	Maximum Duty Cycle		62	67	72	%
V_{GATE-L}	Output Voltage Low	V_{DD}=15V, I_o=20mA			1.4	V
V_{GATE-H}	Output Voltage High	V_{DD}=13.5V, I_o=20mA	8			V
t_r	Rising Time	V_{DD}=15V, C_L=1nF		150		ns
t_f	Falling Time	V_{DD}=15V, C_L=1nF		55		ns
$V_{GATE-CLAMP}$	Output Clamp Voltage	V_{DD}=22V	16	17	18	V

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Typical Performance Characteristics

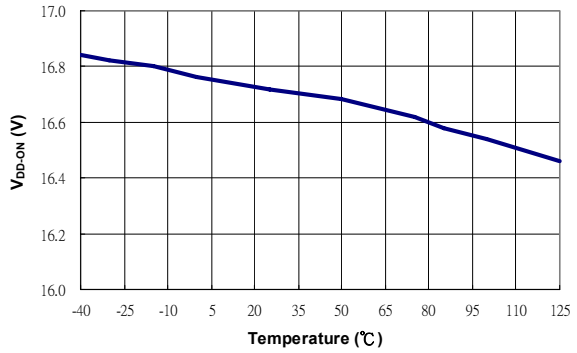


Figure 4. Turn-on Threshold Voltage (V_{DD-ON}) vs. Temperature

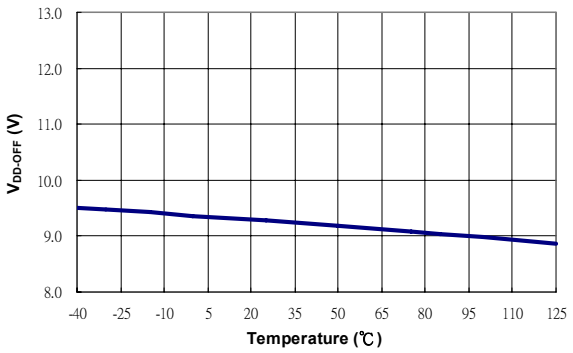


Figure 5. Turn-off Threshold Voltage (V_{DD-ON}) vs. Temperature

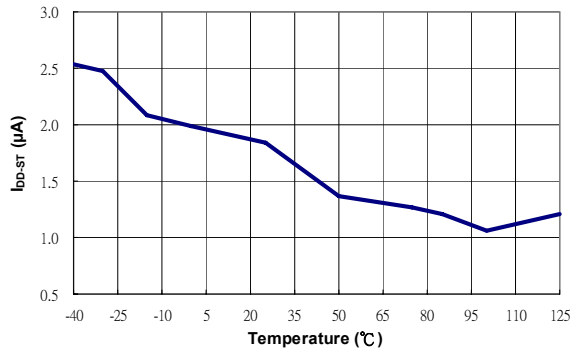


Figure 6. Start-up Current (I_{DD-ST}) vs. Temperature

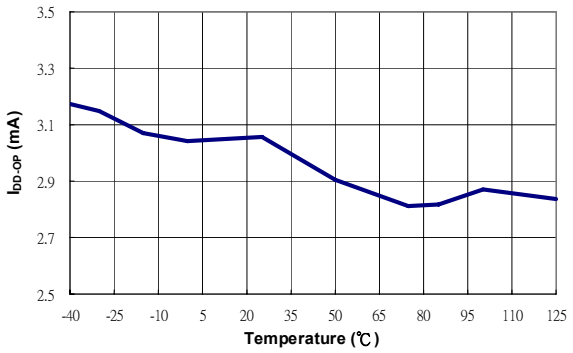


Figure 7. Operating Supply Current (I_{DD-OP}) vs. Temperature

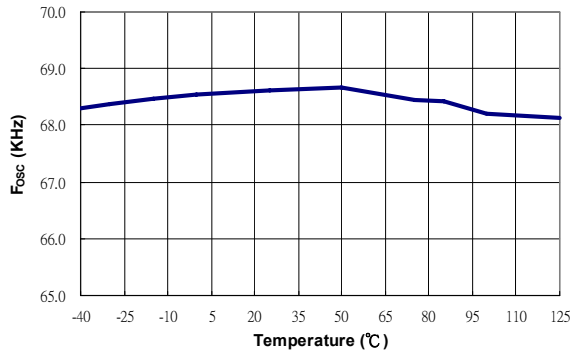


Figure 8. Center Frequency (F_{OSC}) vs. Temperature

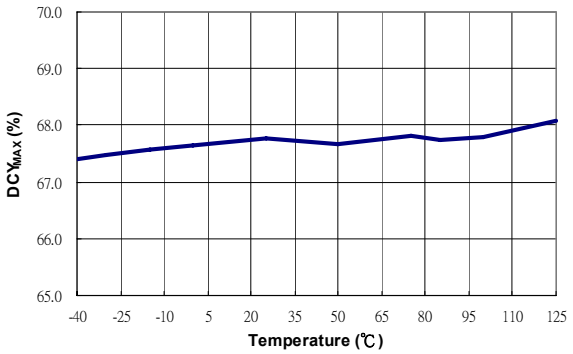


Figure 9. Maximum Duty Cycle (DCY_{MAX}) vs. Temperature

Typical Performance Characteristics

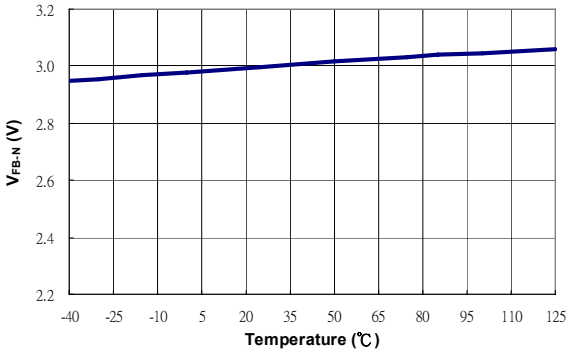


Figure 10. Green-Mode Entry FB Voltage (V_{FB-N}) vs. Temperature

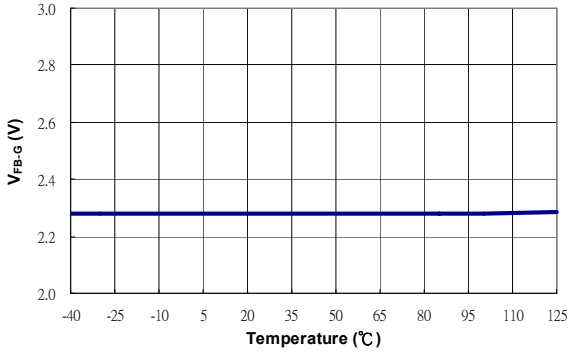


Figure 11. Green-Mode Ending FB Voltage (V_{FB-G}) vs. Temperature

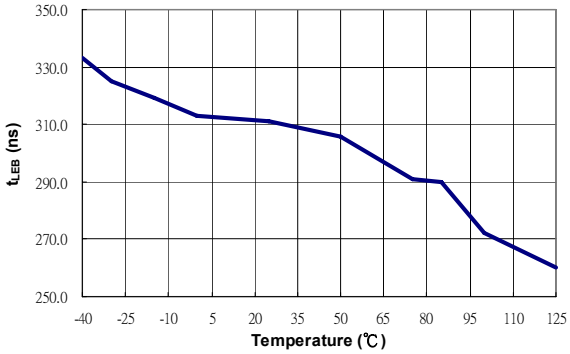


Figure 12. Leading-Edge Blanking Time (t_{LEB}) vs. Temperature

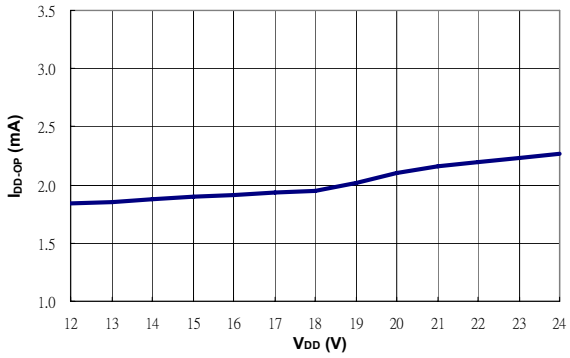


Figure 13. Operating Supply Current vs. V_{DD} Voltage

Operation Description

SG6859A devices integrate many useful designs into one controller for low-power, switch-mode power supplies. The following descriptions highlight some of the features of the SG6859A series.

Start-up Current

The start-up current is only 9μA. Low start-up current allows a start-up resistor with high resistance and low-wattage to supply the start-up power for the controller. A 1.5MΩ, 0.25W, start-up resistor and a 10μF/25V V_{DD} hold-up capacitor are sufficient for an AC-to-DC power adapter with a wide input range ($100V_{AC}$ to $240V_{AC}$).

Operating Current

The operating current has been reduced to 3mA. The low operating current results in higher efficiency and reduces the VDD hold-up capacitance requirement.

Green-Mode Operation

The proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load conditions. On-time is limited to provide stronger protection against brownouts and other abnormal conditions. The feedback current, which is sampled from the voltage feedback loop, is taken as the reference. Once the feedback current exceeds the threshold current, the switching frequency starts to decrease. This green-mode function dramatically reduces power consumption under light-load and zero-load conditions. Power supplies using the SG6859A can meet even the strictest regulations regarding standby power consumption.

Oscillator Operation

A resistor connected from the RI pin to ground generates a constant current source used to charge an internal capacitor. The charge time determines the internal clock speed and the switching frequency. Increasing the resistance reduces the amplitude of the input current and the switching frequency. A 95kΩ R_I resistor results in a 50μA constant current I_I and a 70kHz switching frequency. The relationship between R_I and the switching frequency is:

$$f_{PWM} = \frac{6650}{R_I(k\Omega)}(kHz) \quad (1)$$

Leading-Edge Blanking

Each time the power MOSFET is switched on, a turn-on spike occurs at the sense-resistor. To avoid premature termination of the switching pulse, a 320ns leading-edge blanking time is built in. Conventional RC filtering can be omitted. During this blanking period, the current-limit comparator is disabled and cannot switch off the gate driver.

Constant Output Power Limit

When the SENSE voltage across the sense resistor, R_S, reaches the threshold voltage (around 1V), the output GATE drive is turned off following a short propagation delay, t_{PD}. This propagation delay introduces an additional current proportional to $t_{PD} \cdot V_{IN}/L_P$. The propagation delay is nearly constant, regardless of the input line voltage V_{IN}. Higher input line voltages result in larger additional currents. At high input line voltages, the output power limit is higher than at low input line voltages. To compensate for this output power limit variation across a wide AC input range, the threshold voltage is adjusted by adding a positive ramp. This ramp signal rises from 0.8V to 1V, then flattens out at 1V. A smaller threshold voltage forces the output GATE drive to terminate earlier, which reduces the total PWM turn-on time and makes the output power equal to that of low line input. This proprietary internal compensation ensures a constant output power limit for a wide AC input voltage range ($90V_{AC}$ to $264V_{AC}$).

Under-Voltage Lockout (UVLO)

The turn-on and turn-off thresholds are fixed internally at 16.5V and 9.5V. During start-up, the hold-up capacitor must be charged to 16.5V through the start-up resistor to enable the SG6859A. The hold-up capacitor continues to supply VDD until power can be delivered from the auxiliary winding of the main transformer. V_{DD} must not drop below 9.5V during this start-up process. This UVLO hysteresis window ensures that hold-up capacitor is adequate to supply V_{DD} during start-up.

Gate Output

The BiCMOS output stage is a fast totem pole gate driver. Cross conduction has been avoided to minimize heat dissipation, increase efficiency, and enhance reliability. The output driver is clamped by an internal 17V Zener diode to protect power MOSFET transistors against undesired over-voltage gate signals.

Built-in Slope Compensation

The sensed voltage across the current-sense resistor is used for current-mode control and pulse-by-pulse current limiting. Built-in slope compensation improves stability and prevents sub-harmonic oscillations due to peak-current mode control. The SG6859A has a synchronized, positively-sloped ramp built-in at each switching cycle. The slope of the ramp is:

$$\frac{0.36 \times \text{Duty}}{\text{Duty(max.)}} \quad (2)$$

Noise Immunity

Noise from the current sense or the control signal can cause significant pulse-width jitter, particularly in continuous-conduction mode (CCM). While slope compensation helps alleviate these problems, further precautions should still be taken. Good placement and layout practices should be followed. Avoiding long PCB traces and component leads, locating compensation and filter components near the SG6859A, and increasing power MOS gate resistance improve performance.

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Applications Information

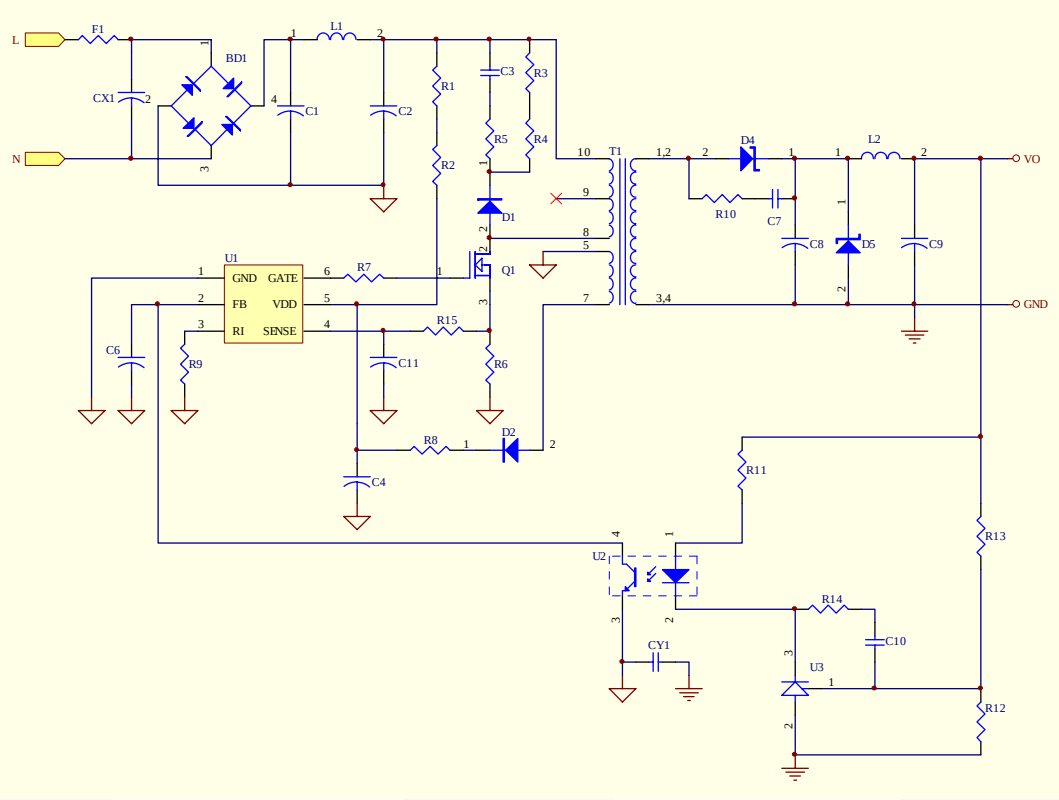


Figure 14. Reference Circuit

BOM

Reference	Component	Reference	Component
BD1	BD 1A/500V	L2	10μH 6mm
CX1 (Optional)	XC 0.1μF	Q1	MOSFET 1A/600V
CY1 (Optional)	YC 102P/400V (Y1)	R1,R2	R 750KΩ 1206
C1	CC 103P/500V	R3,R4	R 47KΩ 1206
C2	EC 10μF/400V 105°C	R5	R 47Ω 1206
C3	CC 102P/500V	R6	R 4.7Ω 1206
C4	EC 10μF/50V	R7	R 100Ω 0805
C6	CC 472P 0805	R8	R 10Ω 1206
C7 (Optional)	CC 102P/100V 1206	R9	R 100KΩ 0805
C8	EC 470μF/10V 105°C	R10 (Optional)	R 10Ω 1206
C9	EC 220μF/10V 105°C	R11	R 100Ω 1/8W
C10	CC 222P 0805	R12	R 33KΩ 0805
C11	N.C.	R13	R 33KΩ 1/8W
D1	Diode FRI07	R14	R 4.7KΩ 0805
D2	Diode FR102	R15	R 0Ω 0805
D4	Diode SB360	T1	EE-16
D5 (Optional)	ZD 6.8V 0.5W	U1	IC SG6859A
F1	R 1Ω/0.5W	U2	PC817
L1	20mH 6•8mm	U3	TL431

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Physical Dimensions

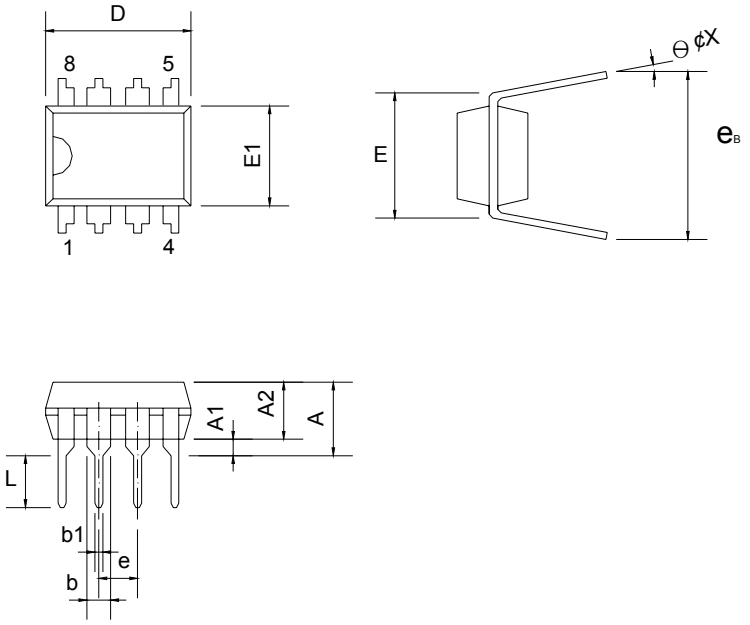


Figure 15. 8-Pin Dip-8 Package

Dimensions

Symbol	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			5.334			0.210
A1	0.381			0.015		
A2	3.175	3.302	3.429	0.125	0.130	0.135
b		1.524			0.060	
b1		0.457			0.018	
D	9.017	9.271	10.160	0.355	0.365	0.400
E		7.620			0.300	
E1	6.223	6.350	6.477	0.245	0.250	0.255
e		2.540			0.100	
L	2.921	3.302	3.810	0.115	0.130	0.150
e_B	8.509	9.017	9.525	0.335	0.355	0.375
θ°	0°	7°	15°	0°	7°	15°

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Physical Dimensions (Continued)

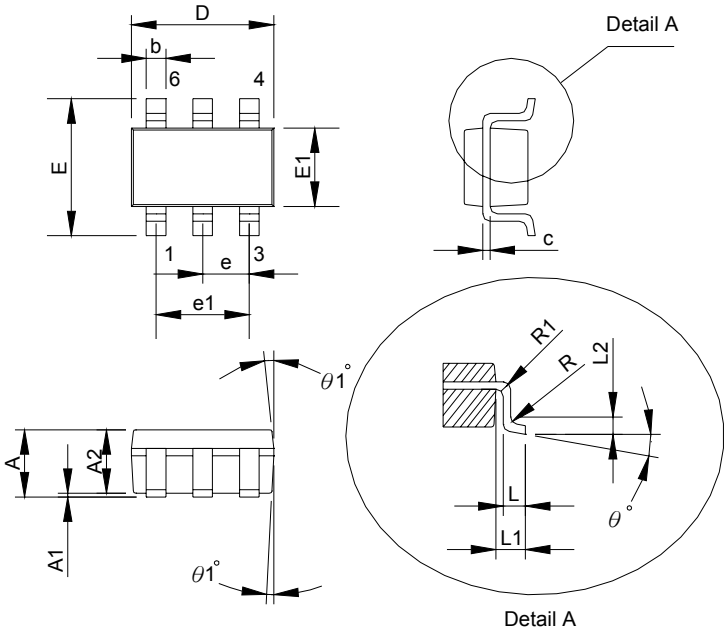


Figure 16. 6-Pin SOT-26 Package

Dimensions

Symbol	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.45			0.057
A1			0.15			0.006
A2	0.90	1.15	1.30	0.036	0.045	0.051
b	0.30		0.50	0.011		0.020
c	0.08		0.22	0.003		0.009
D		2.90			0.114	
E		2.80			0.110	
E1		1.60			0.063	
e		0.95			0.037	
e1		1.90			0.075	
L	0.30	0.45	0.60	0.020	0.018	0.024
L1		0.60			0.024	
L2		0.25			0.010	
R	0.10			0.004		
R1	0.10		0.25	0.004		0.010
θ°	0°	4°	8°	0°	4°	8°
θ1°	5°	10°	15°	5°	10°	15°

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Green FPS™
Green FPS™ e-Series™
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SuperSOT™-6
SuperSOT™-8
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